



Ultra-High Voltage Protection USB2 1:2 Mux/DeMux

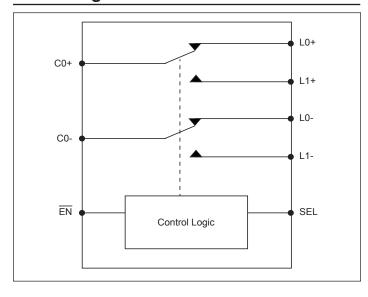
Description

The DIODES PI3USB4000A is a 2-to-1 differential channel multiplexer/demultiplexer switch. C0+/C0- pins can tolerate voltages up to 18V. Over-voltage protection (OVP) is implemented at 4.75V to immediately switch off the channels when over-voltage condition is detected. PI3USB4000A can pass USB2.0 signal with bandwidth 1GHz to maintain signal integrity and eye diagram open.

Application(s)

- Smart Phones
- Type-C Applications
- Tablets
- NBs
- PCs

Block Diagram



Features

- Differential Bi-Directional 2:1 Mux/DeMux
- Wide Input Voltage Range: 0V to 5.5V
- Wide Bandwidth: 1GHz
 - Ultra-Low Con: 7pF
 - Ultra-Low Ron: 5Ω (typical)
- Low Propagation Delay, 0.25ns typical
- Low Off-Isolation, -30dB@240MHz
- Low Crosstalk: -35dB@240MHz,
- Low Power Consumption: 35μA typical
- Wide Supply Voltage 2.7-5.5V
- Supports 1.8V Logic on Control Pins
- Protection Feature
 - Off-Protection for Current Leakage in Power-Down Mode
 - All I/O Pins are High Voltage Tolerance
 - C0+/C0- Tolerance to 18V
 - Lx+/- Tolerance to 6V
 - V_{DD} Tolerance to 9V
 - Over-Voltage Protection when V bus Short to C0-/C0+ When Device is Power-On and Enabled
- ESD Protection On (C0+/-)
 - □ IEC61000-4-2
- Wide Temperature Range: -40°C to 85°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- Packaging (Pb-free & Green):
 - 10-contact, UQFN (ZUA10), 1.5x2mm, 0.5mm(H), 0.6mm
 pitch
 - 10-contact, UQFN (ZM10), 1.4x1.8mm, 0.55mm(H), 0.4mm
 pitch

Notes:

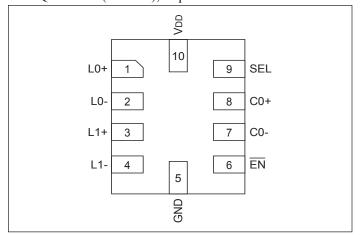
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
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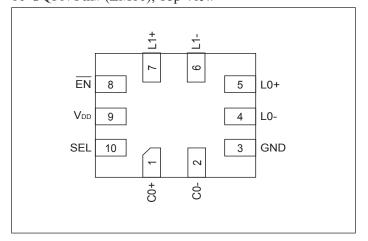


Pin Configuration

10-UQFN Pin# (ZUA10), Top View



10-UQFN Pin# (ZM10), Top View



Pin Description

Pin# (ZUA10)	Pin# (ZM10)	Pin Name	Signal Type	Description	
8,	1,	C0+,	I/O	Signal I/O, Common Port	
7	2	C0-	1/0	Signal 1/O, Common Port	
3,	7,	L1+,	I/O	Circul I/O Channel 1	
4	6	L1-	I/O	Signal I/O, Channel 1	
1,	5,	L0+,	I/O	Signal I/O Channel O	
2	4	L0-	I/O	Signal I/O, Channel 0	
9	10	SEL	I	Operation mode Select (when SEL = 0: C0 \rightarrow L0, when SEL = 1: C0 \rightarrow L1)	
6	8	EN	$\overline{\text{EN}} = 1$, Power down is enabled. Please see Truth Table.		
10	9	V_{DD}	Pwr	Positive Supply Voltage	
5	3	GND	Pwr	Power ground	

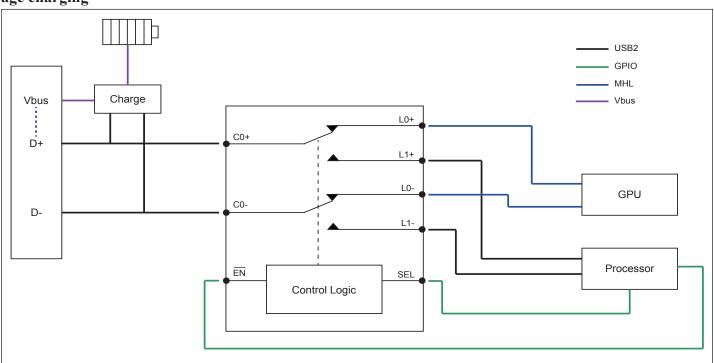
Truth Table

Function	SEL	EN
C0+/- to L0+/-	L	L
C0+/- to L1+/-	Н	L
All Switches Hi-z	X	Н





$PI3USB4000A\ application\ in\ MHL\ Switching\ and\ provide\ overvoltage\ protection\ for\ D+/-\ when\ high\ voltage\ charging$







Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Supply Voltage (VDD) to Ground Potential	0.3V to +9V
Channel Input/Output Voltage (Lx+/-)	0.3V to +6V
Channel Input/Output Voltage (C0+/-)	0.3V to +18V
Control Pins Input Voltage (EN/SEL)	0.3V to +6V
ESD (All Pins)2	KV (HBM) and 1KV (CDM)
Channel Input/Output Current (Lx/C0)	±50mA
Junction Temperature	125°C
1	

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Description	Test Conditions	Min.	Тур.	Max.	Units
V_{DD}	Power Supply		2.7	3.3	6.0	V
V _{IO}	Analog Voltage Range		0		5.5	V
$V_{\rm I}$	Voltage Range for Control Pins		0		5.5	V
I_{DD}	Current Consumption in Normal Operation	$V_{DD} = 3.3V$, $V_{\underline{IO}} = 0V$, SEL = GND or V_{DD} , $\overline{EN} = Low$		35	45	μА
I _{DD_OVP}	Current Consumption in OVP	$V_{\rm DD}$ = 3.3V, $V_{\rm C0+}/V_{\rm C0-}$ = 5.5V, SEL = GND or $V_{\rm DD}$, EN = Low		35		μА
I_{DDQ}	Chip Disabled Current Consumption	$V_{DD} = 3.3V$, $V_{\underline{IO}} = 0V$, SEL = GND or V_{DD} , $\overline{EN} = High$		1	2	μА
T_{A}	Operating Temperature Range		-40		85	°C

DC Electrical Characteristics for Switching over Operating Range

 $T_A = -40$ °C to 85°C, Typical values are at $V_{DD} = 3.3$ V, $T_A = 25$ °C, (unless otherwise noted)

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units		
Control Pins - EN	Control Pins - EN/SEL							
V _{IH} - cntrl signals	Input HIGH Voltage for SEL and $\overline{\text{EN}}$	$V_{\rm DD} = 2.7-5.5 V$	1.2			V		
V _{IL} - cntrl signals	Input LOW Voltage for SEL and EN	$V_{\rm DD} = 2.7-5.5 V$			0.6	V		
I _{IH}	Input HIGH Current for SEL and EN	$V_{\rm I} = 0-5.5 \rm V$	-1		1	μΑ		
I_{IL}	Input LOW Current for SEL and EN	$V_{\rm I} = 0-5.5{\rm V}$	-1		1	μΑ		
High Speed IO – L	High Speed IO – L0/L1/C0							
V _{OVP}	OVP trigger voltage		4.6	4.75	5.0	V		
Ron	ON resistance	$V_{I/O} = 0V$, 0.4V, $I_{on} = -8 \text{ mA}$		5	8	Ω		
Δ Ron	On resistance between + and - channel	$V_{I/O} = 0V, 0.4V, I_{on} = -8 \text{ mA}$		0.5	1	Ω		
Ron_Flat	ON resistance flatness	$V_{I/O} = 0V, 0.4V, I_{on} = -8 \text{ mA}$		0.2	0.5	Ω		
I _{off}	Power-off leakage	$V_{\rm DD} = 0V$, $V_{\rm I/O} = 0 - 3.6V$	-1		1	μΑ		
I _{OC}	Channel off leakage current	$\overline{\rm EN} = {\rm V_{DD}} = 3.3 {\rm V}, {\rm V_{I/O}} = 0\text{-}3.6 {\rm V}$	-1		1	μΑ		





Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
I _{ON}	Channel on leakage current	$\overline{\rm EN} = 0 \rm V, \rm V_{\rm DD} = 3.3 \rm V, \rm V_{\rm I/O} = 0 \rm -3.6 \rm V$	-1		1	μΑ
I _{OVP}	Leakage current on C0+/C0- in OVP mode	$\overline{\rm EN} = 0 \rm V, V_{\rm DD} = 3.3 \rm V, V_{\rm C0+} \rm or $		3	15	μΑ

Dynamic Electrical Characteristics

 $T_A = -40$ °C to 85 °C, Typical values are at $V_{DD} = 3.3$ V, $T_A = 25$ °C, (unless otherwise noted)

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units	
Control Pins – E	Control Pins – EN/SEL						
C _I	Input capacitance	F = 1MHz		5		pF	
High Speed IO -	L0/L1/C0						
Con	ON Capacitance	f = 1MHz		7		pF	
Coff	OFF Capacitance	f = 1MHz		9		pF	
DDIL	Insertion Loss	f = 240MHz		-0.5		dB	
DDRL	Differential Return Loss	f = 240MHz		-15		dB	
DDOI	Differential OFF Isolation	f = 240MHz		-30		dB	
DDOI		f = 100kHz		-80		dB	
DDXT	Differential Crosstalk	f = 240MHz		-35		dB	
BW	-3dB Bandwidth			1		GHz	

Switching Characteristics⁽¹⁾

 $T_A = -40^{\circ} C$ to $85^{\circ} C$, Typical values are at $V_{DD} = 3.3 V$, $T_A = 25^{\circ} C$, (unless otherwise noted)

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
t _{OVP}	OVP Response Time ⁽¹⁾	$R_{LX} = 600\Omega$, time from the voltage on $C0\pm = 4{\sim}6V$ to the voltage on $L_X\pm = 4.75$		0.5	1	μs
t _{PZH} , t _{PZL}	Line Enable Time			20		μs
$t_{\mathrm{PHZ}}, t_{\mathrm{PLZ}}$	Line Disable Time	Con Tost Cinquit for Electrical		50		ns
t _{Pd}	Propagation Delay	See Test Circuit for Electrial Characteristics		250		ps
t _{b-b}	Bit-to-bit Skew Within the Same Dif- ferential Pair ⁽¹⁾			8	20	ps
Ton	Device Enable Time			100		μs
$T_{ m off}$	Device Disable Time			50		ns

Note:

1. Guaranteed by design.



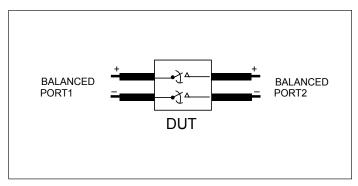


Figure 1. Differential Insertion Loss Setup

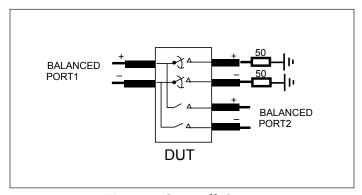


Figure 3. Crosstalk Setup

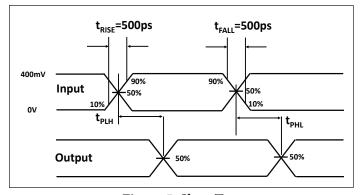


Figure 5. Skew Test

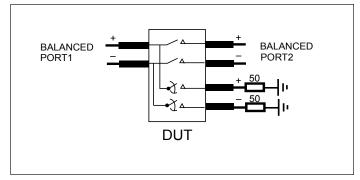


Figure 2. Off-Isolation Setup

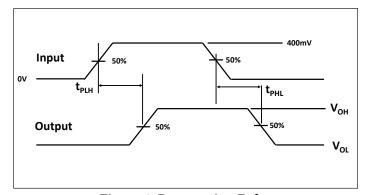
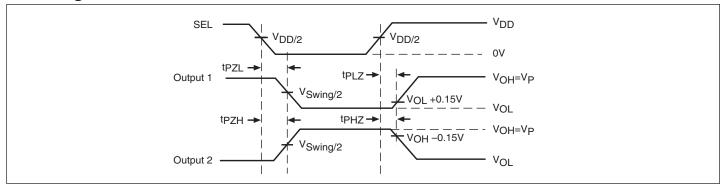


Figure 4. Propagation Delay



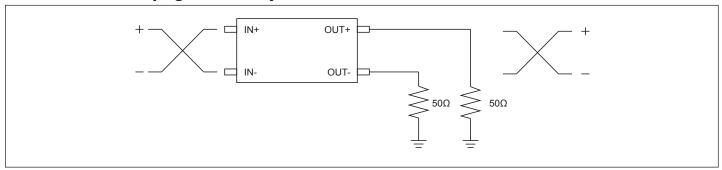


Switching Waveforms

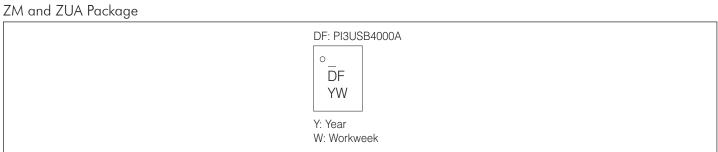


Voltage Waveforms Enable and Disable Times

Test Circuit for Propagation Delay



Part Marking

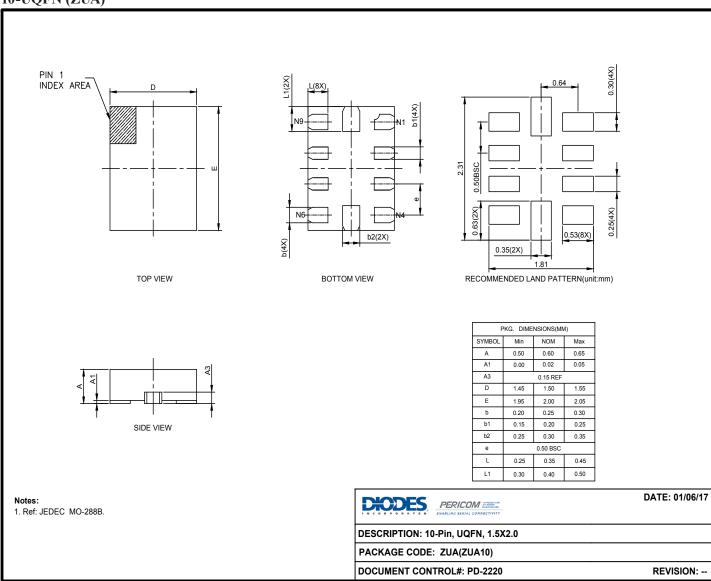






Packaging Mechanical

10-UQFN (ZUA)

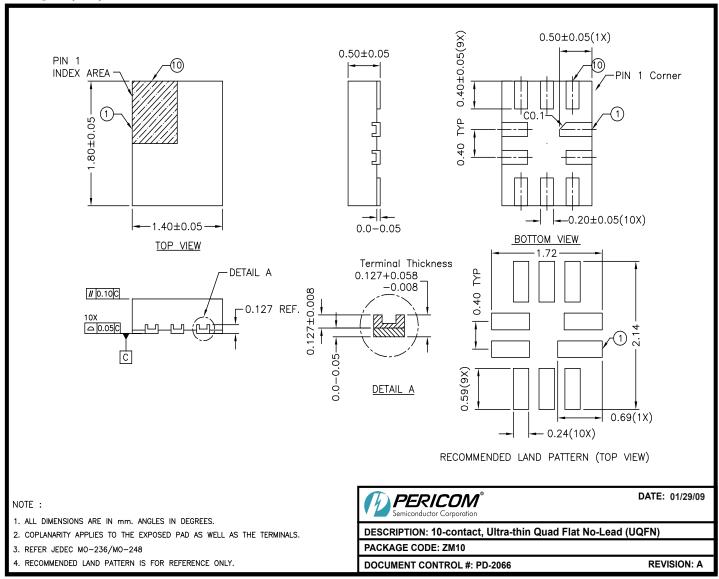


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10-UQFN (ZM)



09-0072

For latest package info.

 $please\ check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-mechanicals-and-thermal-characteristics/pericom-packaging-pericom-$

Ordering Information

Ordering Code	Package Code	Package Description
PI3USB4000AZUAEX	ZUA	10-Pin, 1.5x2.0 (UQFN)
PI3USB4000AZMEX	ZM	10-contact, Ultra-thin Quad Flat No-Lead (UQFN)

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- $2. \ See \ https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.$
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel





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